

AOZ8831DT-24

Ultra Low Capacitance One-line
Bi-directional TVS Diode

General Description

The AOZ8831-24 is an ultra low capacitance one-line bi-directional transient voltage suppressor diode designed to protect high speed data lines and voltage sensitive electronics from high transient conditions and ESD.

This device incorporates one TVS diode in an ultra-small DFN 1.0 x 0.6 package. It may be used to meet the ESD immunity requirements of IEC 61000-4-2, Level 4 (±15kV air, ±13kV contact discharge).

The AOZ8831-24 comes in an RoHS compliant DFN package and is rated over a -40°C to +125°C ambient temperature range.

The ultra-small $1.0 \times 0.6 \times 0.4$ mm DFN package makes it ideal for applications where PCB space is a premium. The small size and high ESD protection makes it ideal for protecting voltage sensitive electronics from high transient conditions and ESD.

Features

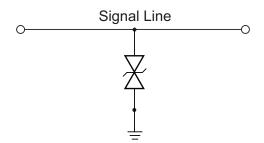
- ESD protection for high-speed data lines:
 - Exceeds: IEC 61000-4-2 (ESD) ±15kV (air), ±13kV (contact)
 - Human Body Model (HBM) ±15kV
- Small package saves board space
- Ultra low capacitance: 0.35pF
- Low clamping voltage
- Operating voltage: 24V
- Pb-free device

Applications

- Portable handheld devices
- Notebook computers
- Digital Cameras
- Portable GPS



Typical Application



Bidirection Protection of Single Line

Pin Configuration





Ordering Information

Part Number	Ambient Temperature Range	Package	Environmental		
AOZ8831DT-24	-40°C to +125°C	DFN 1.0 x 0.6	Green Product		



AOS Green Products use reduced levels of Halogens, and are also RoHS compliant. Please visit www.aosmd.com/media/AOSGreenPolicy.pdf for additional information.

Absolute Maximum Ratings

Exceeding the Absolute Maximum ratings may damage the device.

Parameter	Rating
VP – VN	24V
Peak Pulse Current (I _{PP}), t _P = 8/20μs	1.2A
Peak Pulse Power, t _P = 8/20μs	60W
Storage Temperature (T _S)	-65°C to +150°C
ESD Rating per IEC61000-4-2, Contact ⁽¹⁾	±13kV
ESD Rating per IEC61000-4-2, Air ⁽¹⁾	±15kV
ESD Rating per Human Body Model ⁽²⁾	±15kV

Notes:

- 1. IEC 61000-4-2 discharge with C_Discharge = 150pF, R_Discharge = 330 Ω .
- 2. Human Body Discharge per MIL-STD-883, Method 3015 $C_{Discharge}$ = 100pF, $R_{Discharge}$ = 1.5k Ω .

Maximum Operating Ratings

	Parameter	Rating
ĺ	Junction Temperature (T _J)	-40°C to +125°C



Electrical Characteristics

T_A = 25°C unless otherwise specified.

Symbol	Parameter	Diagram
I _{PP}	Maximum Reverse Peak Pulse Current ⁽³⁾ (100ns Transmission Line Pulse (TLP))	1
V _{CL}	Clamping Voltage @ I _{PP} ⁽³⁾	Ipp
V _P	Peak Voltage (IEC61000-4-5 8/20µs, Surge Current I _{PEAK} = 1A)	V _{CL} V _{BR} V _{RWM}
V _{RWM}	Working Peak Reverse Voltage	VCLVBR VHWM IR VRWM VBR VCL II VRWM VBR VCL
I _R	Maximum Reverse Leakage Current	
V _{BR}	Breakdown Voltage	
CJ	Capacitance @ V _R = 0 and f = 1MHz	I

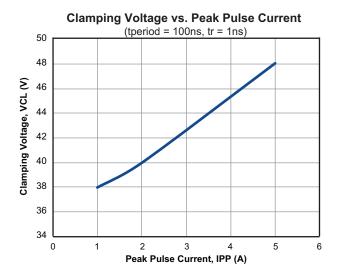
	Device	V _{DMM} (V)	V _{CL} Max.		_{RWM} (V) V _{BR} (V) I _R (μA)		V _{CL} Max			V _P (V)		C _J (pF)	
Device	Marking	Max.	Min.			I _{PP} = 1A	I _{PP} = 2A	I _{PP} = 5A	Max.	Min.	Тур.	Max.	
AOZ8831DT-24	2	24	26	0.1	38	40	48	45	0.2	0.35	0.5		

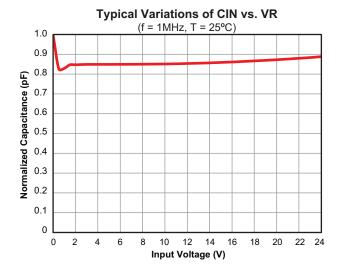
Notes:

 $\ensuremath{\mathtt{3}}.$ These specifications are guaranteed by design and characterization.



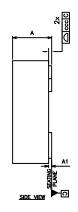
Typical Performance Characteristics

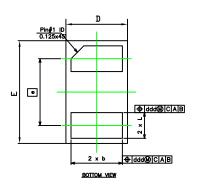




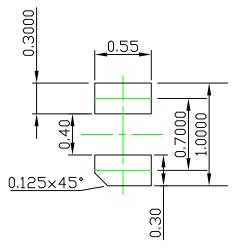


Package Dimensions, DFN 1.0 x 0.6





RECOMMENDED LAND PATTERN

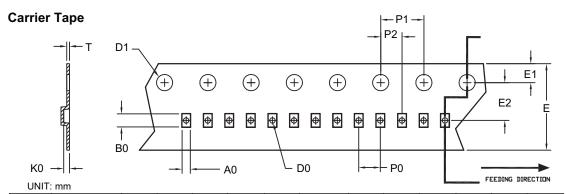


UNIT: mm

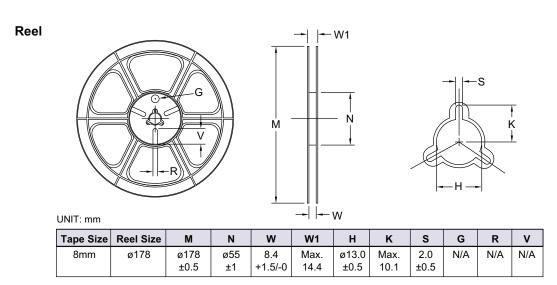
SYMBOLS	DIMENS	IONS IN MIL	LIMETERS	DIMENSIONS IN INCHES			
	MIN	NDM	MAX	MIN	NDM	MAX	
Α	0.31	0.38	0.40	0.012	0.015	0.016	
A1	0.00	0.02	0.05	0.000	0.001	0.002	
b	0.45	0.50	0.55	0.018	0.020	0.022	
D	0.55	0.60	0.65	0.022	0.024	0.026	
E	0.95	1.00	1.05	0.037	0.039	0.041	
e		0.65 BS	С		0.026 BS	C	
L	0.20	0.25	0.30	0.008	0.010	0.012	
ccc		0.03			0.001		
ddd		0.10			0.004		

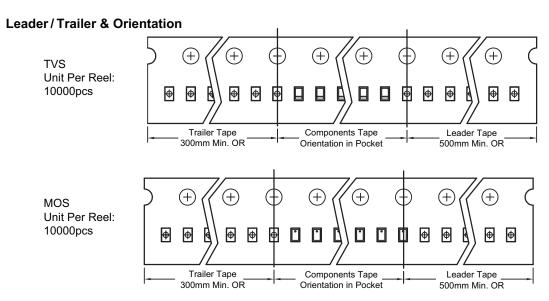


Tape and Reel Dimensions, DFN 1.0 x 0.6



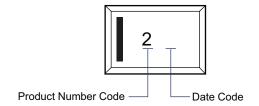
Option	Package	Α0	В0	K0	D0	D1	E	E1	E2	P0	P1	P2	Т
А	DFN 1.0x0.6/ DFN 1.0x0.6A (8 mm)	0.69 ±0.05	1.19 ±0.05	0.66 ±0.05	0.40 ±0.05	1.50 ±0.10	8.00 +0.3/-0.1	1.75 ±0.10	3.50 ±0.05	2.00 ±0.05	4.00 ±0.10	0.20 ±0.05	0.23 ±0.02
В	DFN 1.0x0.6/ DFN 1.0x0.6A (8 mm)	0.65 ±0.04	1.05 ±0.04	0.61 ±0.04	0.40 ±0.05	1.50 ±0.10	8.00 +0.3/-0.1	1.75 ±0.10	3.50 ±0.05	2.00 ±0.10	4.00 ±0.10	0.20 ±0.05	0.20 ±0.05







Part Marking



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